PNP/NPN Epitaxial Planar Silicon Transistors



2SB1142/2SD1682

50V/2.5A High-Speed Switching Applications

Applications

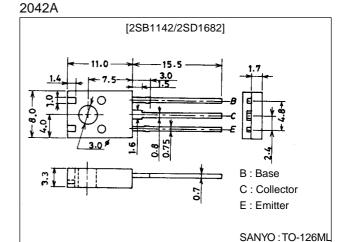
· Power supplies, relay drivers, lamp drivers.

Features

- · Adoption of FBET, MBIT processes.
- · Low saturation voltage.
- · Large current capacity and wide ASO.

Package Dimensions

unit:mm



():2SB1142

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		(–)60	V
Collector-to-Emitter Voltage	VCEO		(–)50	V
Emitter-to-Base Voltage	VEBO		(–)6	V
Collector Current	IC		(–)2.5	A
Collector Current (Pulse)	I _{CP}		(–)5.0	A
Collector Dissipation	PC		1.5	W
		Tc=25°C	10	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings			Unit
Falameter				min	typ	max	Unit
Collector Cutoff Current	ICBO	CB=(-)50V, IE=0				(–)100	nA
Emitter Cutoff Current	IEBO	EB=(-)4V, IC=0				(–)100	nA
DC Current Gain	h _{FE} 1	⁷ CE=(-)2V, I _C =(-)100mA		(100)*		(400)*	
				100*		560	
	h _{FE} 2	CE=(-)2V, IC=(-)2A		35			
Gain-Bandwidth Product	fT	CE=(-)10V, IC=(-)50mA			140		MHz
* : The 2SB1142/2SD1682 are classified by 100mA h_{FE} as follows : 2SB1142 100 R 200 140 S 280 200				200 T	400	•	
		2SD1682 100 R 200 140) S 280	200 T	400	280 L	J 560

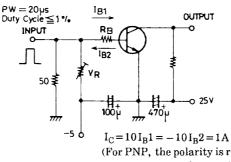
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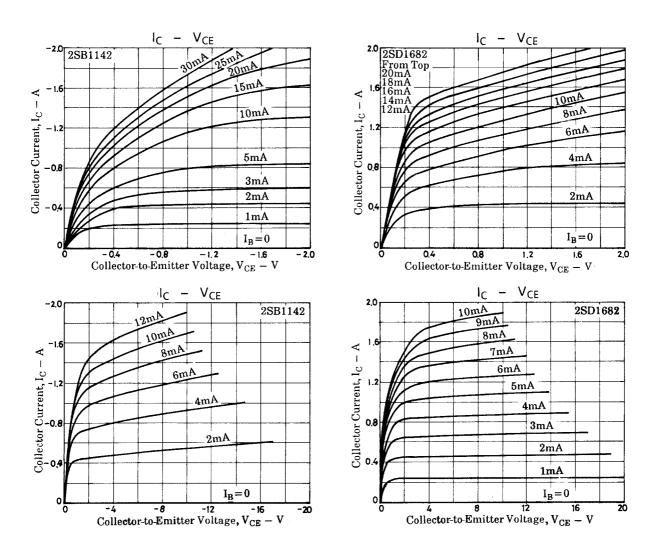
2SB1142/2SD1682

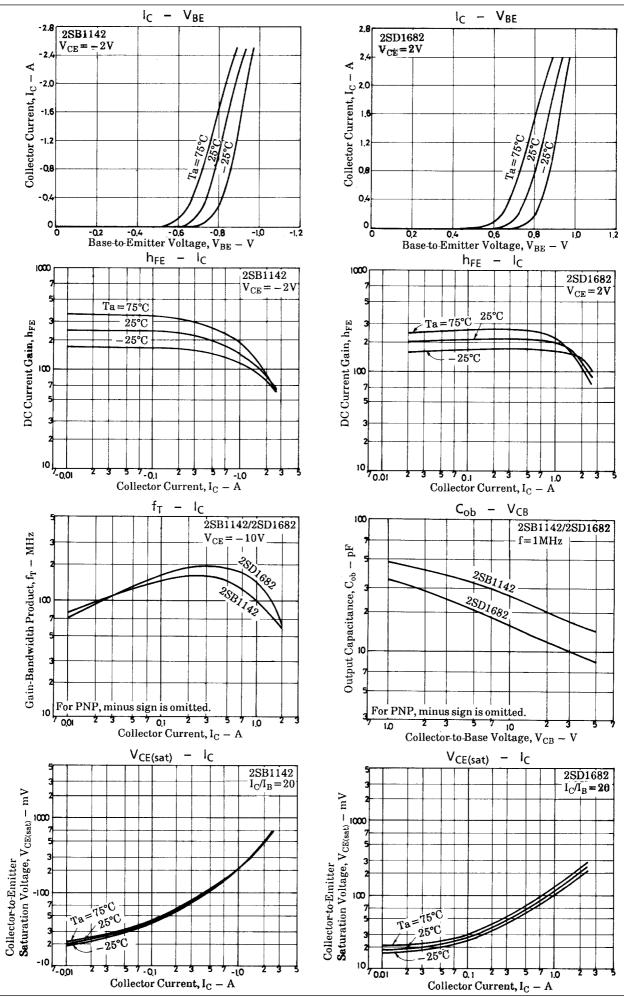
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =(-)1A, I _B =(-)50mA		(–250)	(500)	mV
				110	300	mV
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =(-)1A, I _B =(-)50mA		(–)0.85	(–)1.2	V
Output Capacitance	C _{ob}	V _{CB} =(-)10V, f=1MHz		(25)16		pF
Collector-to-Base Breakdown Voltage	V _(BR) CBO	I _C =(-)10µA, I _E =0	(–)60			V
Collector-to-Emitter Breakdown Voltage	V _(BR) CEO	I _C =(−)1mA, R _{BE} =∞	(–)50			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E =(-)10μA, I _C =0	(–)6			V
Turn-ON Time	ton	See specified Test Circuit		(35)35		ns
Storage Time	^t stg	See specified Test Circuit		(350)		ns
				550		ns
Fall Time	tf	See specified Test Circuit		(30)30		ns

Switching Time Test Circuit



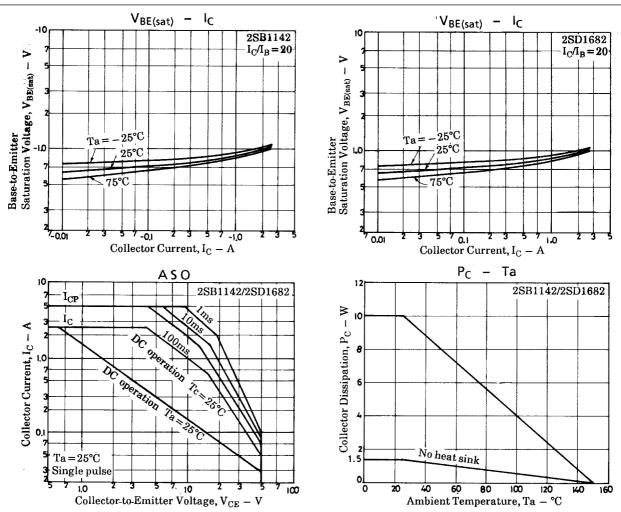
(For PNP, the polarity is reversed). Unit (resistance : Ω , capacitance : F)





No.2060-3/4

2SB1142/2SD1682



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